

QL12X16B
pASIC® 1 Family
Very-High-Speed CMOS FPGA

Rev C

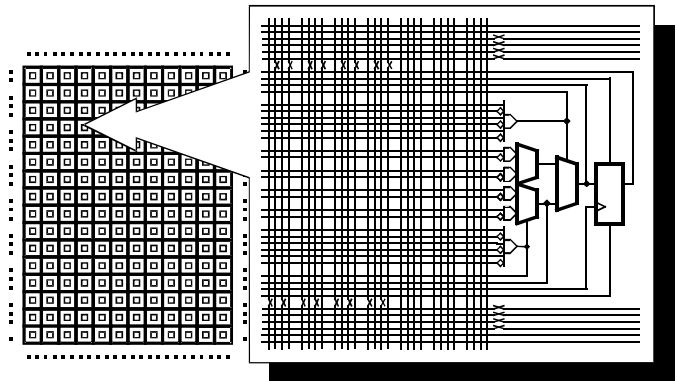
pASIC
HIGHLIGHTS

...2,000
usable ASIC gates,
88 I/O pins

QL12x16B
Block Diagram

192 Logic Cells

- ☒ **Very High Speed** – ViaLink® metal-to-metal programmable-via antifuse technology, allows counter speeds over 150 MHz and logic cell delays of under 2 ns.
- ☒ **High Usable Density** – A 12-by-16 array of 192 logic cells provides 2,000 usable ASIC gates (4,000 PLD gates) in 68-pin and 84-pin PLCC, 84-pin CPGA and 100-pin TQFP packages.
- ☒ **Low-Power, High-Output Drive** – Standby current typically 2 mA. A 16-bit counter operating at 100 MHz consumes less than 50 mA. Minimum IOL of 12 mA and IOH of 8 mA
- ☒ **Low-Cost, Easy-to-Use Design Tools** – Designs entered and simulated using QuickLogic's new QuickWorks® development environment, or with third-party CAE tools including Viewlogic, Synopsys, Mentor, Cadence and Veribest. Fast, fully automatic place and route on PC and workstation platforms using QuickLogic software.



▪ = Up to 80 prog. I/O cells, 6 Input high-drive cells, 2 Input/Clk (high-drive) cells



**PRODUCT SUMMARY**

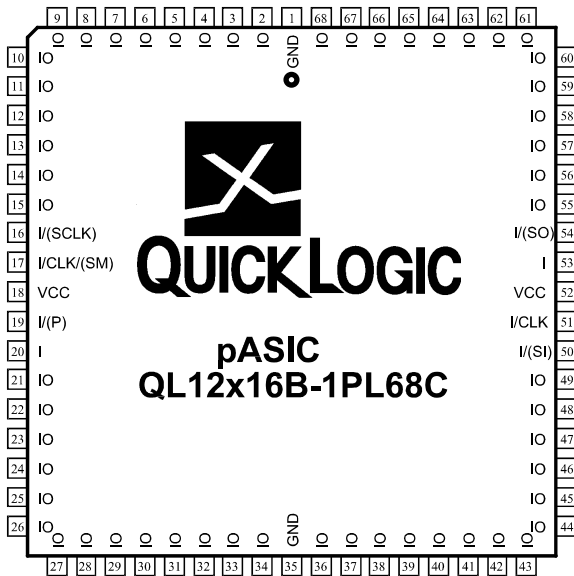
The QL12x16B is a member of the pASIC 1 Family of very-high-speed CMOS user-programmable ASIC devices. The 192 logic cell field-programmable gate array (FPGA) offers 2,000 usable ASIC gates (4,000 usable PLD gates) of high-performance general-purpose logic in a wide variety of package configurations.

Low-impedance, metal-to-metal, ViaLink interconnect technology provides nonvolatile custom logic capable of operating above 150 MHz. Logic cell delays under 2 ns, combined with input delays of under 1.5 ns and output delays under 3 ns, permit high-density programmable devices to be used with today's fastest microprocessors and DSPs.

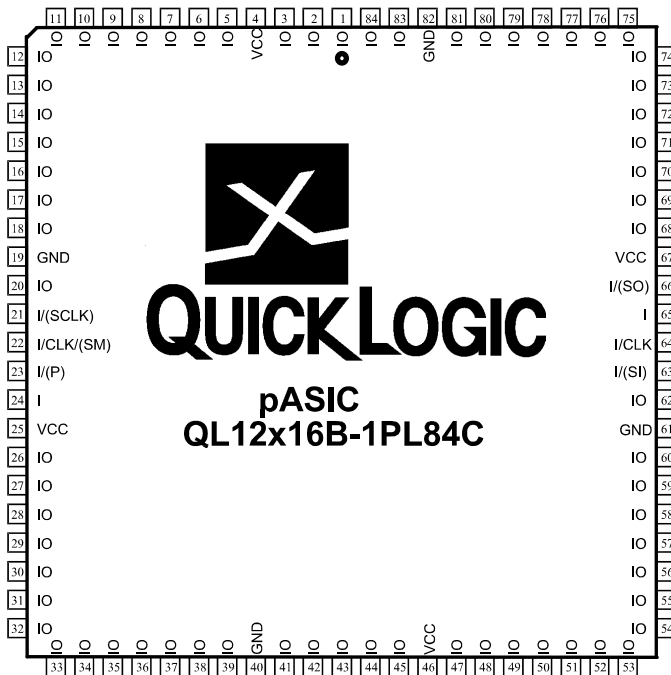
Designs can be entered using QuickLogic's QuickWorks Toolkit or most popular third-party CAE tools. QuickWorks combines Verilog/VHDL design entry and simulation tools with device-specific place & route and programming software. Ample on-chip routing channels allow fast, fully automatic place and route of designs using up to 100% of the logic and I/O cells, while maintaining fixed pin-outs.

FEATURES

- ✕ Total of 88 I/O pins
 - 80 Bidirectional Input/Output pins
 - 6 Dedicated Input/High-Drive pins
 - 2 Clock/Dedicated input pins with fanout-independent, low-skew clock networks
- ✕ Input + logic cell + output delays under 6 ns
- ✕ Chip-to-chip operating frequencies up to 110 MHz
- ✕ Internal state machine frequencies up to 150 MHz
- ✕ Clock skew < 0.5 ns
- ✕ Input hysteresis provides high noise immunity
- ✕ Built-in scan path permits 100% factory testing of logic and I/O cells and functional testing with Automatic Test Vector Generation (ATVG) software after programming
- ✕ Available in 68-pin and 84-pin PLCC, 84-pin CPGA and 100-pin TQFP packages
- ✕ 68-pin PLCC compatible with QL8x12B
- ✕ 84-pin PLCC compatible with QL16x24B
- ✕ 100-pin TQFP compatible with QL8x12B and QL16x24B
- ✕ 0.65 μ CMOS process with ViaLink programming technology



Pinout Diagram
68-pin PLCC



Pinout Diagram
84-pin PLCC

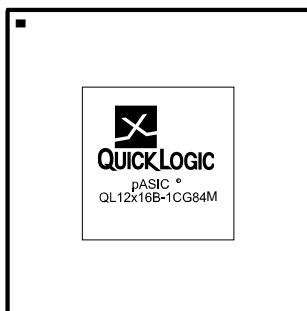
Pins identified I/SCLK, SM, SO and SI are used during scan path testing operation.

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pASIC 1

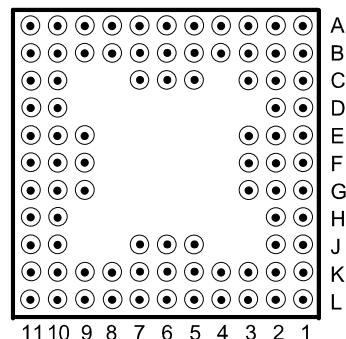


**Pinout Diagram
84-pin CPGA**

TOP VIEW

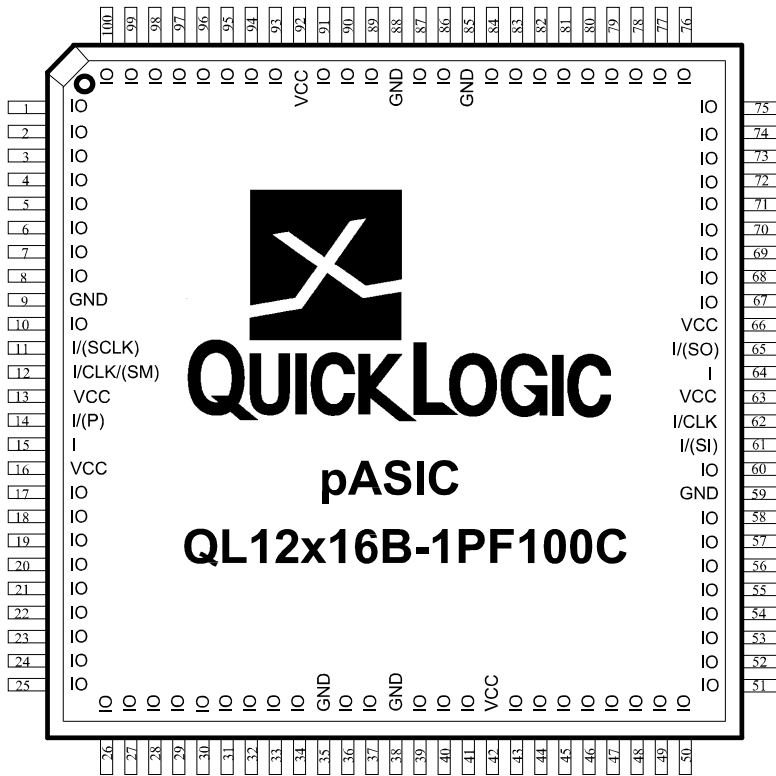


BOTTOM VIEW



CPGA 84 Function/Connector Pin Table

PIN	FUNC	PIN	FUNC	PIN	FUNC	PIN	FUNC
B10	IO	B2	IO	K2	IO	K10	IO
B9	IO	C2	IO	K3	IO	J10	IO
A10	IO	B1	IO	L2	IO	K11	IO
A9	IO	C1	IO	L3	IO	J11	IO
B8	IO	D2	IO	K4	IO	H10	IO
A8	IO	D1	IO	L4	IO	H11	IO
A7	IO	E1	IO	L5	IO	G11	IO
C7	GND	E3	GND	J5	GND	G9	GND
A6	IO	E2	IO	L6	IO	G10	IO
B7	I/(SCLK)	F1	IO	K5	I/(SI)	F11	IO
C6	I/CLK/(SM)	F2	IO	J6	I/CLK	F10	IO
B6	I(P)	F3	IO	K6	I	F9	IO
B5	I	G1	IO	K7	I/(SO)	E11	IO
C5	VCC	G3	VCC	J7	VCC	E9	VCC
A5	IO	G2	IO	L7	IO	E10	IO
A4	IO	H1	IO	L8	IO	D11	IO
B4	IO	H2	IO	K8	IO	D10	IO
A3	IO	J1	IO	L9	IO	C11	IO
A2	IO	K1	IO	L10	IO	B11	IO
B3	IO	J2	IO	K9	IO	C10	IO
A1	IO	L1	IO	L11	IO	A11	IO



Pinout Diagram
100-pin TQFP

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pASIC 1

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage -0.5 to 7.0V
 Input Voltage -0.5 to VCC +0.5V
 ESD Pad Protection ±2000V
 DC Input Current ±20 mA
 Latch-up Immunity ±200 mA

Storage Temperature -65°C to + 150°C
 Lead Temperature 300°C

OPERATING RANGE

Symbol	Parameter	Military		Industrial		Commercial		Unit	
		Min	Max	Min	Max	Min	Max		
VCC	Supply Voltage	4.5	5.5	4.5	5.5	4.75	5.25	V	
TA	Ambient Temperature	-55		-40	85	0	70	°C	
TC	Case Temperature		125					°C	
K	Delay Factor	-X Speed Grade			0.4	2.75	0.46	2.55	
		-0 Speed Grade	0.39	1.82	0.4	1.67	0.46	1.55	
		-1 Speed Grade	0.39	1.56	0.4	1.43	0.46	1.33	
		-2 Speed Grade			0.4	1.35	0.46	1.25	

DC CHARACTERISTICS over operating range

Symbol	Parameter	Conditions	Min	Max	Unit
VIH	Input HIGH Voltage		2.0		V
VIL	Input LOW Voltage			0.8	V
VOH	Output HIGH Voltage	IOH = -4 mA	3.7		V
		IOH = -8 mA	2.4		V
		IOH = -10 µA	VCC-0.1		V
VOL	Output LOW Voltage	IOL = 12 mA*		0.4	V
		IOL = 10 µA		0.1	V
II	Input Leakage Current	VI = VCC or GND	-10	10	µA
IOZ	3-State Output Leakage Current	VI = VCC or GND	-10	10	µA
CI	Input Capacitance [1]			10	pF
IOS	Output Short Circuit Current [2]	VO = GND	-10	-80	mA
		VO = VCC	30	140	mA
ICC	D.C. Supply Current [3]	VI, VIO = VCC or GND		10	mA

*IOL = 12 mA for commercial range only. IOL = 8 mA for the industrial and military ranges.

Notes:

- [1] Capacitance is sample tested only. CI = 20 pF max on I(SI).
- [2] Only one output at a time. Duration should not exceed 30 seconds.
- [3] Commercial temperature grade only. Maximum Icc for industrial grade is 15mA and for military grade is 20 mA. For AC conditions use the formula described in the Section 9 — Power vs Operating Frequency.
- [4] Stated timing for worst case Propagation Delay over process variation at VCC = 5.0V and TA = 25°C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.
- [5] These limits are derived from a representative selection of the slowest paths through the pASIC logic cell *including net delays*. Worst case delay values for specific paths should be determined from timing analysis of your particular design.



AC CHARACTERISTICS at VCC = 5V, TA = 25°C (K = 1.00)

Logic Cell

Symbol	Parameter	Propagation Delays (ns)				
		Fanout				
		1	2	3	4	8
tPD	Combinatorial Delay [5]	1.7	2.2	2.6	3.2	5.2
tSU	Setup Time [5]	2.1	2.1	2.1	2.1	2.1
tH	Hold Time	0.0	0.0	0.0	0.0	0.0
tCLK	Clock to Q Delay	1.0	1.5	1.9	2.5	4.6
tCWHI	Clock High Time	2.0	2.0	2.0	2.0	2.0
tCWLO	Clock Low Time	2.0	2.0	2.0	2.0	2.0
tSET	Set Delay	1.7	2.1	2.6	3.2	5.2
tRESET	Reset Delay	1.5	1.9	2.2	2.7	4.3
tSW	Set Width	1.9	1.9	1.9	1.9	1.9
tRW	Reset Width	1.8	1.8	1.8	1.8	1.8

Input Cells

Symbol	Parameter	Propagation Delays (ns) [4]					
		1	2	3	4	6	8
tIN	High Drive Input Delay [6]	2.4	2.5	2.6	2.7	3.0	3.3
tINI	High Drive Input, Inverting Delay [6]	2.5	2.6	2.7	2.8	3.1	3.4
tIO	Input Delay (bidirectional pad)	1.4	1.9	2.2	2.8	3.7	4.6
tGCK	Clock Buffer Delay [7]	2.7	2.8	2.8	2.9	2.9	3.0
tGCKHI	Clock Buffer Min High [7]	2.0	2.0	2.0	2.0	2.0	2.0
tGCKLO	Clock Buffer Min Low [7]	2.0	2.0	2.0	2.0	2.0	2.0

Output Cell

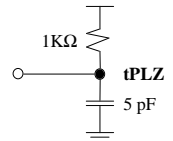
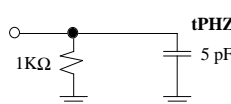
Symbol	Parameter	Propagation Delays (ns) [4]				
		Output Load Capacitance (pF)				
		30	50	75	100	150
tOUTLH	Output Delay Low to High	2.7	3.4	4.2	5.0	6.7
tOUTH	Output Delay High to Low	2.8	3.7	4.7	5.6	7.6
tPZH	Output Delay Tri-state to High	4.0	4.9	6.1	7.3	9.7
tPZL	Output Delay Tri-state to Low	3.6	4.2	5.0	5.8	7.3
tPHZ	Output Delay High to Tri-state [8]	2.9				
tPLZ	Output Delay Low to Tri-state [8]	3.3				

Notes:

[6] See High Drive Buffer Table for more information.

[7] Clock buffer fanout refers to the maximum number of flip flops per half column. The number of half columns used does not affect clock buffer delay.

[8] The following loads are used for tPZZ:





High Drive Buffer

Symbol	Parameter	Clock Drivers Wired Together	Propagation Delays (ns) [4]				
			Fanout				
			12	24	48	72	96
tIN	High Drive Input Delay	1	4.5	5.4			
		2		3.9	5.6		
		3			4.5	5.3	6.3
		4				4.6	5.3
tINI	High Drive Input, Inverting Delay	1	4.7	5.6			
		2		4.0	5.8		
		3			4.6	5.5	6.4
		4				4.8	5.5

AC Performance

Propagation delays depend on routing, fanout, load capacitance, supply voltage, junction temperature, and process variation. The AC Characteristics are a design guide to provide initial timing estimates at nominal conditions. Worst case estimates are obtained when nominal propagation delays are multiplied by the appropriate Delay Factor, K, as specified in the Delay Factor table (Operating Range). The effects of voltage and temperature variation are illustrated in the graphs on page 4-47, K Factor versus Voltage and Temperature. The pASIC Development Tools incorporate data sheet AC Characteristics into the QDIF database for pre-place-and-route timing analysis. The SpDE Delay Modeler extracts specific timing parameters for precise path analysis or simulation results following place and route.

ORDERING INFORMATION

QL 12x16B - 1 PF100 C

